

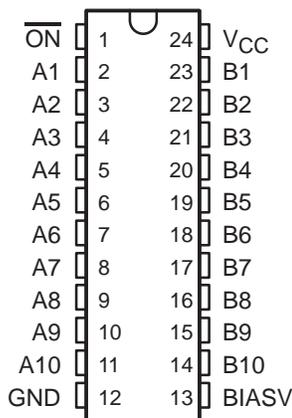
# SN74CBT6800C

## 10-BIT FET BUS SWITCH WITH PRECHARGED OUTPUTS 5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION

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- Member of the Texas Instruments Widebus™ Family
- Undershoot Protection for Off-Isolation on A and B Ports Up to -2 V
- B-Port Outputs Are Precharged by Bias Voltage (BIASV) to Minimize Signal Distortion During Live Insertion and Hot-Plugging
- Supports PCI Hot Plug
- Bidirectional Data Flow, With Near-Zero Propagation Delay
- Low ON-State Resistance ( $r_{on}$ ) Characteristics ( $r_{on} = 3 \Omega$  Typical)
- Low Input/Output Capacitance Minimizes Loading and Signal Distortion ( $C_{iO(OFF)} = 5.5 \text{ pF}$  Typical)
- Data and Control Inputs Provide Undershoot Clamp Diodes
- Low Power Consumption ( $I_{CC} = 3 \mu\text{A}$  Max)
- $V_{CC}$  Operating Range From 4 V to 5.5 V
- Data I/Os Support 0 to 5-V Signaling Levels (0.8-V, 1.2-V, 1.5-V, 1.8-V, 2.5-V, 3.3-V, 5-V)
- Control Inputs Can be Driven by TTL or 5-V/3.3-V CMOS Outputs
- $I_{off}$  Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)
- Supports Both Digital and Analog Applications: PCI Interface, Memory Interleaving, Bus Isolation, Low-Distortion Signal Gating

DB, DBQ, DGV, DW, OR PW PACKAGE  
(TOP VIEW)



### description/ordering information

The SN74CBT6800C is a high-speed TTL-compatible FET bus switch with low ON-state resistance ( $r_{on}$ ), allowing for minimal propagation delay. Active Undershoot-Protection Circuitry on the A and B ports of the SN74CBT6800C provides protection for undershoot up to -2 V by sensing an undershoot event and ensuring that the switch remains in the proper OFF state. The device also precharges the B port to a user-selectable bias voltage (BIASV) to minimize live-insertion noise.



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**description/ordering information (continued)**

The SN74CBT6800C is a 10-bit bus switch with a single output-enable ( $\overline{ON}$ ) input. When  $\overline{ON}$  is low, the 10-bit bus switch is ON, and the A port is connected to the B port, allowing bidirectional data flow between ports. When  $\overline{ON}$  is high, the 10-bit bus switch is OFF, and a high-impedance state exists between the A and B ports. The B port is precharged to BIASV through the equivalent of a 10-k $\Omega$  resistor when  $\overline{ON}$  is high, or if the device is powered down ( $V_{CC} = 0$  V).

During insertion (or removal) of a card into (or from) an active bus, the card's output voltage may be close to GND. When the connector pins make contact, the card's parasitic capacitance tries to force the bus signal to GND, creating a possible glitch on the active bus. This glitching effect can be reduced by using a bus switch with precharged bias voltage (BIASV) of the bus switch equal to the input threshold voltage level of the receivers on the active bus. This method will ensure that any glitch produced by insertion (or removal) of the card will not cross the input threshold region of the receivers on the active bus, minimizing the effects of live-insertion noise.

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down,  $\overline{ON}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

**ORDERING INFORMATION**

TA	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	SOIC – DW	Tube	SN74CBT6800CDW	CBT6800C
		Tape and reel	SN74CBT6800CDWR	
	SSOP – DB	Tube	SN74CBT6800CDB	CT6800C
		Tape and reel	SN74CBT6800CDBR	
	SSOP (QSOP) – DBQ	Tape and reel	SN74CBT6800CDBQR	CBT6800C
	TSSOP – PW	Tube	SN74CBT6800CPW	CT6800C
		Tape and reel	SN74CBT6800CPWR	
	TVSOP – DGV	Tape and reel	SN74CBT6800CDGVR	CT6800C

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).

**FUNCTION TABLE**

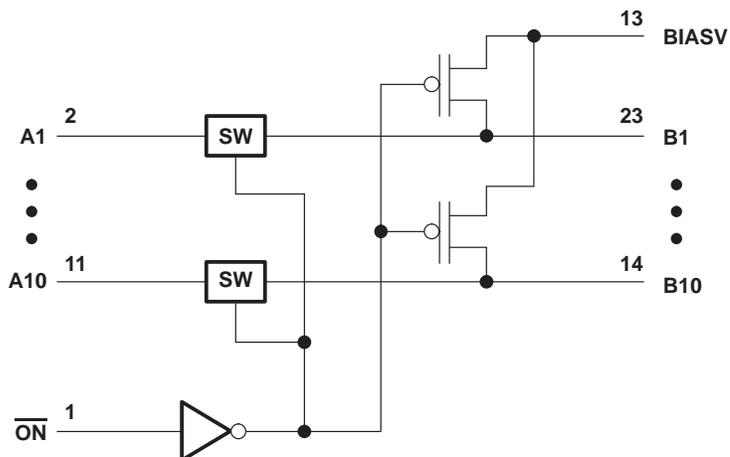
INPUT ON	INPUT/OUTPUT A	FUNCTION
L	B	A port = B port
H	Z	Disconnect B port = BIASV



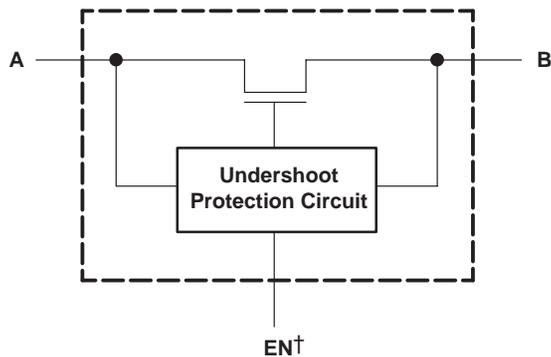
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logic diagram (positive logic)



simplified schematic, each FET switch (SW)



† EN is the internal enable signal applied to the switch.

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**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†**

Supply voltage range, $V_{CC}$	-0.5 V to 7 V
Bias supply voltage range, BIASV	-0.5 V to 7 V
Control input voltage range, $V_{IN}$ (see Notes 1 and 2)	-0.5 V to 7 V
Switch I/O voltage range, $V_{I/O}$ (see Notes 1, 2, and 3)	-0.5 V to 7 V
Control input clamp current, $I_{IK}$ ( $V_{IN} < 0$ )	-50 mA
I/O port clamp current, $I_{I/OK}$ ( $V_{I/O} < 0$ )	-50 mA
ON-state switch current, $I_{I/O}$ (see Note 4)	$\pm 128$ mA
Continuous current through $V_{CC}$ or GND terminals	$\pm 100$ mA
Package thermal impedance, $\theta_{JA}$ (see Note 5): DB package	63°C/W
DBQ package	61°C/W
DGV package	86°C/W
DW package	46°C/W
PW package	88°C/W
Storage temperature range, $T_{stg}$	-65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltages are with respect to ground unless otherwise specified.
  2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
  3.  $V_I$  and  $V_O$  are used to denote specific conditions for  $V_{I/O}$ .
  4.  $I_I$  and  $I_O$  are used to denote specific conditions for  $I_{I/O}$ .
  5. The package thermal impedance is calculated in accordance with JESD 51-7.

**recommended operating conditions (see Note 6)**

	MIN	MAX	UNIT
$V_{CC}$ Supply voltage	4	5.5	V
BIASV Bias supply voltage	0	$V_{CC}$	V
$V_{IH}$ High-level control input voltage	2	5.5	V
$V_{IL}$ Low-level control input voltage	0	0.8	V
$V_{I/O}$ Data input/output voltage	0	5.5	V
$T_A$ Operating free-air temperature	-40	85	°C

NOTE 6: All unused control inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004. BIASV is a supply voltage, not a control input.



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**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)**

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT	
V <sub>IK</sub>	Control inputs	V <sub>CC</sub> = 4.5 V,	I <sub>IN</sub> = -18 mA			-1.8	V	
V <sub>IKU</sub>	Data inputs	V <sub>CC</sub> = 5 V,	0 mA > I <sub>I</sub> ≥ -50 mA, V <sub>IN</sub> = V <sub>CC</sub> or GND, Switch OFF			-2	V	
V <sub>O(USP)‡</sub>		V <sub>CC</sub> = BIASV = 5 V,	I <sub>I</sub> = -10 mA, V <sub>IN</sub> = V <sub>CC</sub> or GND, Switch OFF	3			V	
V <sub>O</sub>	B port	V <sub>CC</sub> = 0 V,	BIASV = V <sub>X</sub> , I <sub>O</sub> = 0	V <sub>X</sub> -0.1		V <sub>X</sub>	V	
I <sub>IN</sub>	Control inputs	V <sub>CC</sub> = 5.5 V,	V <sub>IN</sub> = V <sub>CC</sub> or GND			±1	μA	
I <sub>O</sub>	B port	V <sub>CC</sub> = 4.5 V,	BIASV = 2.4 V, V <sub>O</sub> = 0, Switch OFF, V <sub>IN</sub> = V <sub>CC</sub> or GND		0.25		mA	
I <sub>OZ</sub> §		V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 0 to 5.5 V, V <sub>I</sub> = 0, Switch OFF, V <sub>IN</sub> = V <sub>CC</sub> or GND			±10	μA	
I <sub>off</sub>		V <sub>CC</sub> = 0,	V <sub>O</sub> = 0 to 5.5 V, V <sub>I</sub> = 0			10	μA	
I <sub>CC</sub>		V <sub>CC</sub> = 5.5 V,	I <sub>I/O</sub> = 0, V <sub>IN</sub> = V <sub>CC</sub> or GND, Switch ON or OFF			3	μA	
ΔI <sub>CC</sub> ¶	Control inputs	V <sub>CC</sub> = 5.5 V,	One input at 3.4 V, Other inputs at V <sub>CC</sub> or GND			2.5	mA	
C <sub>in</sub>	Control inputs	V <sub>IN</sub> = 3 V or 0			4		pF	
C <sub>iO(OFF)</sub>	A port	V <sub>I/O</sub> = 3 V or 0,	Switch OFF, V <sub>IN</sub> = V <sub>CC</sub> or GND			5.5	pF	
C <sub>iO(ON)</sub>		V <sub>I/O</sub> = 3 V or 0,	Switch ON, V <sub>IN</sub> = V <sub>CC</sub> or GND			13.5	pF	
r <sub>on</sub> #		V <sub>CC</sub> = 4 V, TYP at V <sub>CC</sub> = 4 V	V <sub>I</sub> = 2.4 V, I <sub>O</sub> = -15 mA		8	12	Ω	
		V <sub>CC</sub> = 4.5 V	V <sub>I</sub> = 0	I <sub>O</sub> = 64 mA		3		6
				I <sub>O</sub> = 30 mA		3		6
			V <sub>I</sub> = 2.4 V, I <sub>O</sub> = -15 mA		5	10		

V<sub>IN</sub> and I<sub>IN</sub> refer to control inputs. V<sub>I</sub>, V<sub>O</sub>, I<sub>I</sub>, and I<sub>O</sub> refer to data pins.

† All typical values are at V<sub>CC</sub> = 5 V (unless otherwise noted), T<sub>A</sub> = 25°C.

‡ V<sub>O(USP)</sub> = A-port undershoot static protection.

§ For I/O ports, the parameter I<sub>OZ</sub> includes the input leakage current.

¶ This is the increase in supply current for each input that is at the specified voltage level, rather than V<sub>CC</sub> or GND.

# Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

**switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)**

PARAMETER	TEST CONDITIONS	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 4 V		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
				MIN	MAX	MIN	MAX	
t <sub>pd</sub>		A or B	B or A		0.24		0.15	ns
t <sub>PZH</sub>	BIASV = GND	$\overline{\text{OE}}$	A or B		6.2	1.5	5.9	ns
t <sub>PZL</sub>	BIASV = 3 V				6.2	1.5	5.9	
t <sub>PHZ</sub>	BIASV = GND	$\overline{\text{OE}}$	A or B		5.6	1.5	6.2	ns
t <sub>PLZ</sub>	BIASV = 3 V				5.6	1.5	6.2	

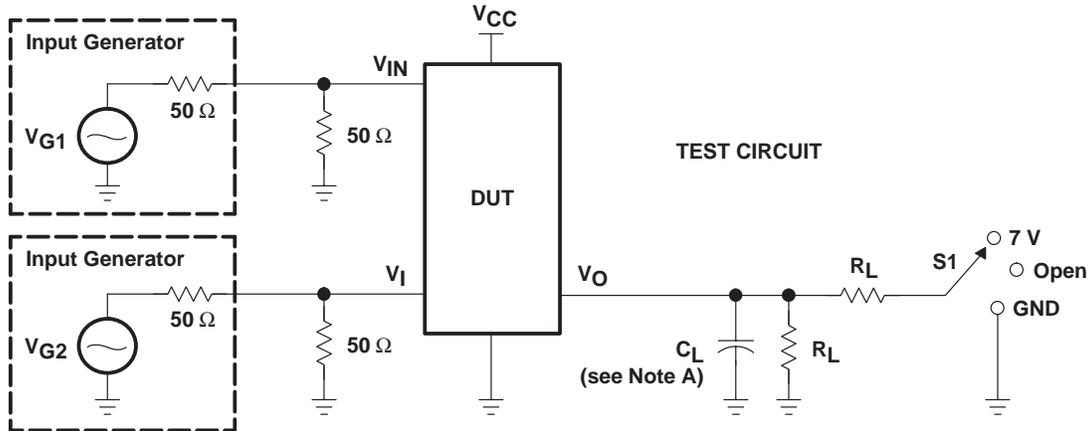
|| The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).



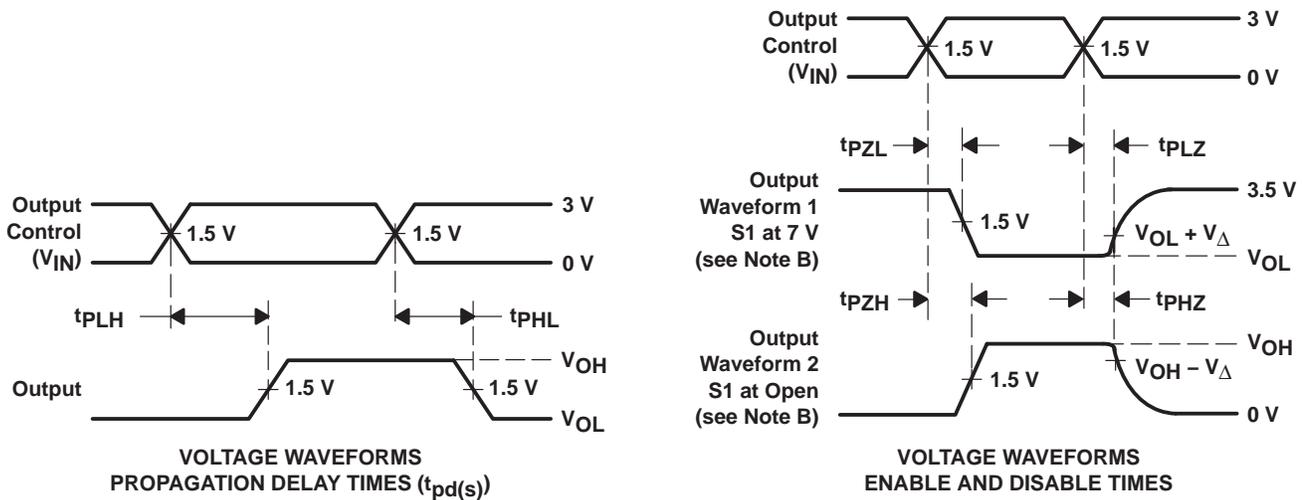
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**PARAMETER MEASUREMENT INFORMATION**



TEST	V <sub>CC</sub>	S1	R <sub>L</sub>	V <sub>I</sub>	C <sub>L</sub>	V <sub>Δ</sub>
t <sub>pd</sub> (s)	5 V ± 0.5 V	Open	500 Ω	V <sub>CC</sub> or GND	50 pF	
	4 V	Open	500 Ω	V <sub>CC</sub> or GND	50 pF	
t <sub>PLZ</sub> /t <sub>PZL</sub>	5 V ± 0.5 V	7 V	500 Ω	GND	50 pF	0.3 V
	4 V	7 V	500 Ω	GND	50 pF	0.3 V
t <sub>PHZ</sub> /t <sub>PZH</sub>	5 V ± 0.5 V	Open	500 Ω	V <sub>CC</sub>	50 pF	0.3 V
	4 V	Open	500 Ω	V <sub>CC</sub>	50 pF	0.3 V



- NOTES:
- A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z<sub>O</sub> = 50 Ω, t<sub>r</sub> ≤ 2.5 ns, t<sub>f</sub> ≤ 2.5 ns.
  - D. The outputs are measured one at a time with one transition per measurement.
  - E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>(s). The t<sub>pd</sub> propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
  - H. All parameters and waveforms are not applicable to all devices.

**Figure 1. Test Circuit and Voltage Waveforms**



**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74CBT6800CDBQRE4	ACTIVE	SSOP	DBQ	24		TBD	Call TI	Call TI	-40 to 85	CBT6800C	<a href="#">Samples</a>
SN74CBT6800CDBQRG4	ACTIVE	SSOP	DBQ	24		TBD	Call TI	Call TI	-40 to 85	CBT6800C	<a href="#">Samples</a>
SN74CBT6800CDGVR	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CT6800C	<a href="#">Samples</a>
SN74CBT6800CDGVRE4	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CT6800C	<a href="#">Samples</a>
SN74CBT6800CDGVRG4	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CT6800C	<a href="#">Samples</a>
SN74CBT6800CDW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT6800C	<a href="#">Samples</a>
SN74CBT6800CDWE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT6800C	<a href="#">Samples</a>
SN74CBT6800CDWG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT6800C	<a href="#">Samples</a>
SN74CBT6800CDWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT6800C	<a href="#">Samples</a>
SN74CBT6800CDWRE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT6800C	<a href="#">Samples</a>
SN74CBT6800CDWRG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBT6800C	<a href="#">Samples</a>
SN74CBT6800CPW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CT6800C	<a href="#">Samples</a>
SN74CBT6800CPWE4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CT6800C	<a href="#">Samples</a>
SN74CBT6800CPWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CT6800C	<a href="#">Samples</a>
SN74CBT6800CPWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CT6800C	<a href="#">Samples</a>
SN74CBT6800CPWRE4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CT6800C	<a href="#">Samples</a>
SN74CBT6800CPWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CT6800C	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "--" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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## TAPE AND REEL INFORMATION



### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CBT6800CDGVR	TVSOP	DGV	24	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74CBT6800CDWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74CBT6800CPWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1

**TAPE AND REEL BOX DIMENSIONS**

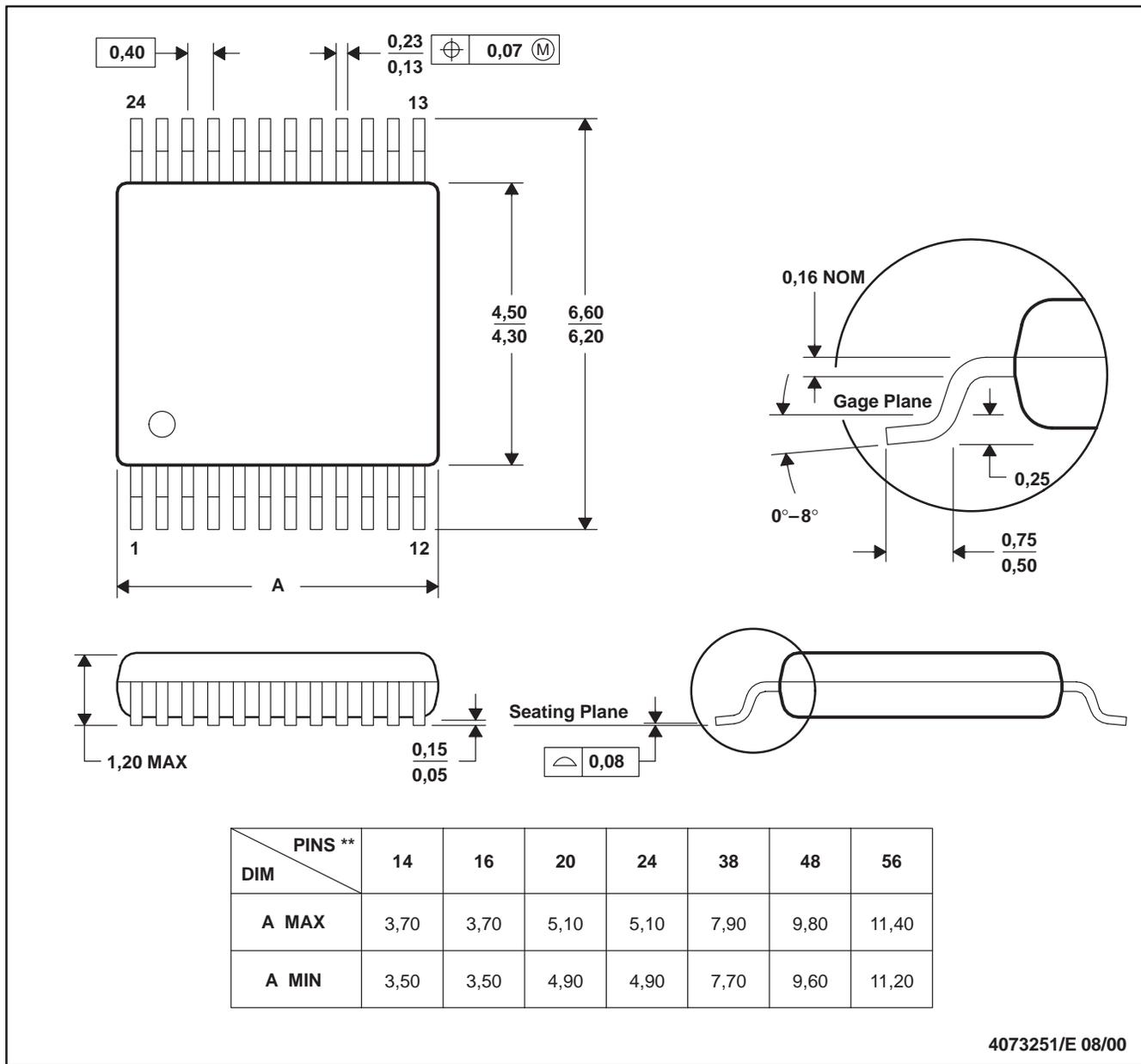

\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74CBT6800CDGVR	TVSOP	DGV	24	2000	367.0	367.0	35.0
SN74CBT6800CDWR	SOIC	DW	24	2000	367.0	367.0	45.0
SN74CBT6800CPWR	TSSOP	PW	24	2000	367.0	367.0	38.0

DGV (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE

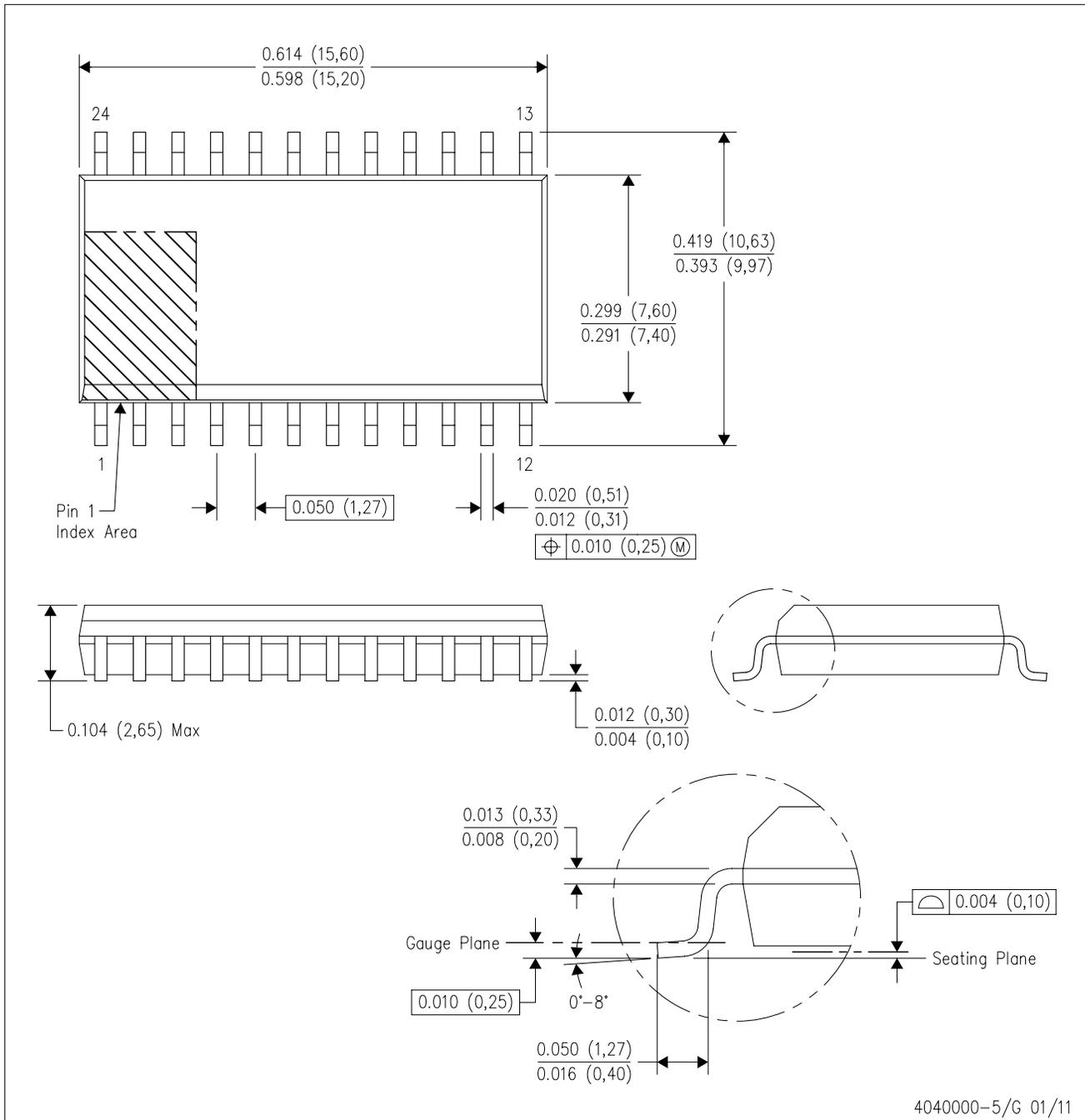
24 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.  
 D. Falls within JEDEC: 24/48 Pins – MO-153  
 14/16/20/56 Pins – MO-194

DW (R-PDSO-G24)

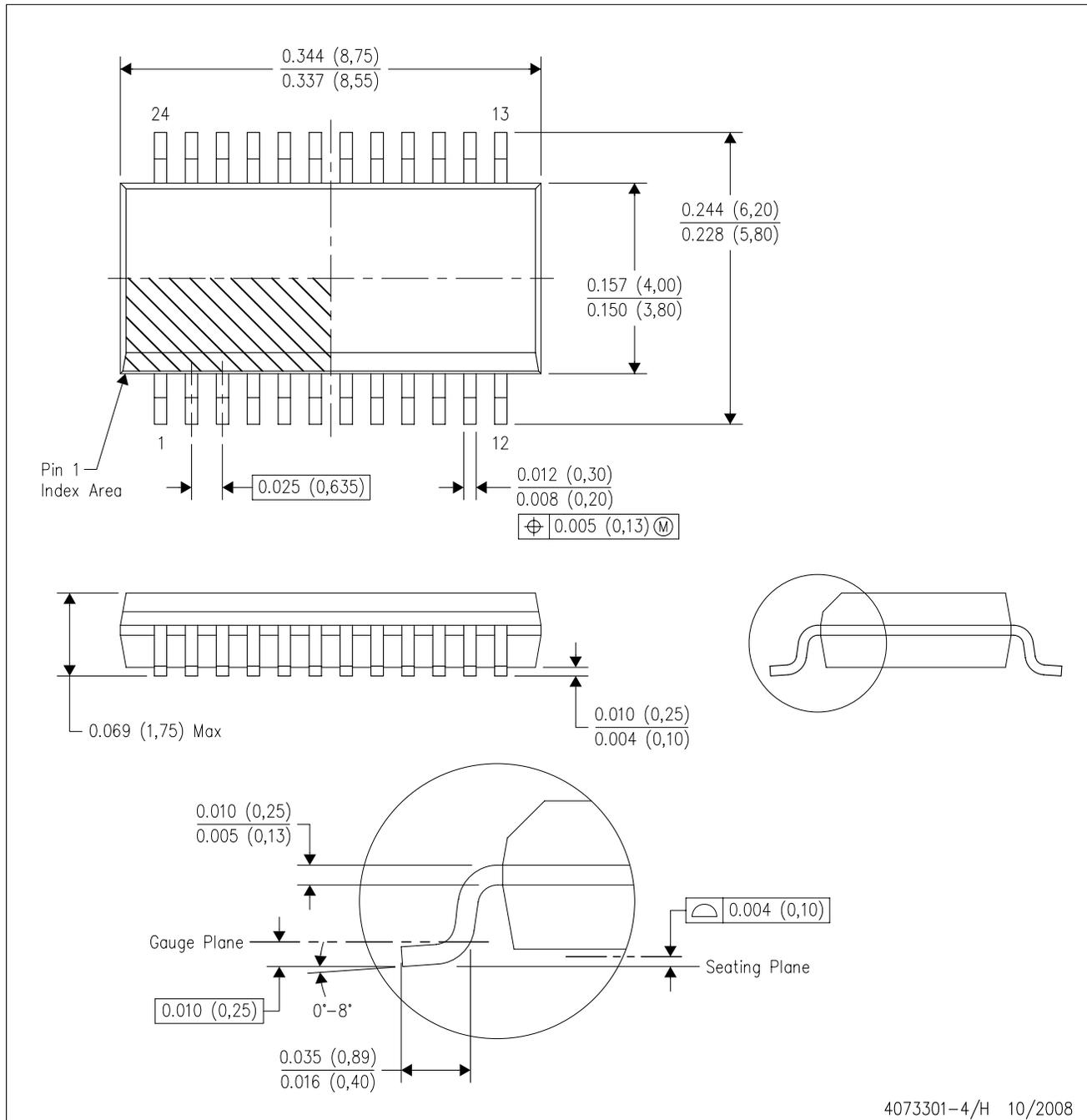
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
  - D. Falls within JEDEC MS-013 variation AD.

DBQ (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE

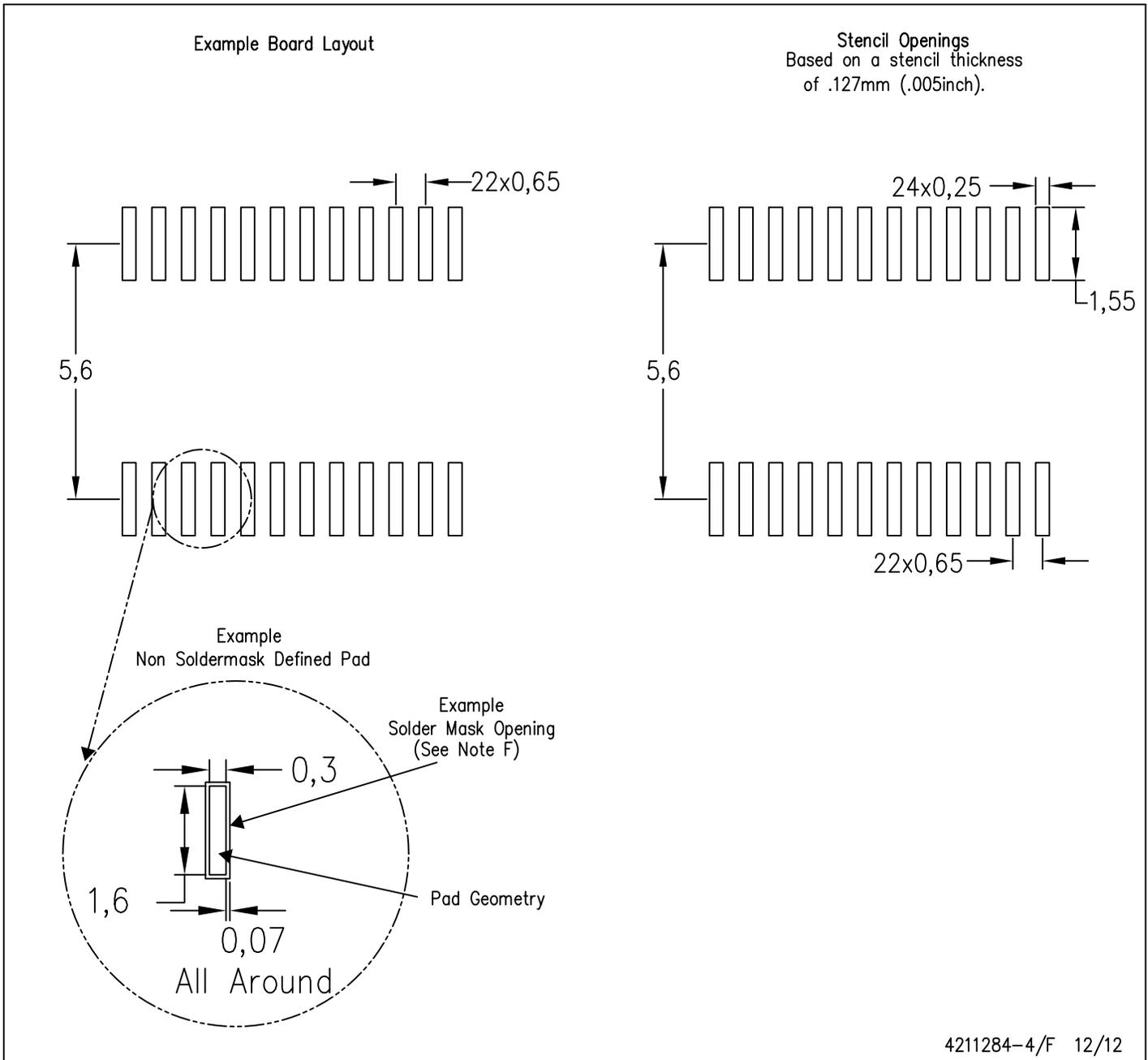


- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
  - D. Falls within JEDEC MO-137 variation AE.



PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate design.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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